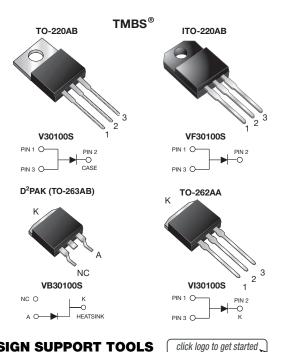
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High Voltage Trench MOS Barrier Schottky Rectifier

Ultra Low $V_F = 0.39 \text{ V}$ at $I_F = 5 \text{ A}$



DESIGN SUPPORT TOOLS



PRIMARY CHARACTERISTICS					
I _{F(AV)}	30 A				
V _{RRM}	100 V				
I _{FSM}	250 A				
V _F at I _F = 30 A	0.69 V				
T _J max.	150 °C				
Package	TO-220AB, ITO-220AB, D ² PAK (TO-263AB),TO-262AA				
Circuit configuration	Single				

FEATURES





- · Low forward voltage drop, low power losses
- · High efficiency operation
- · Low thermal resistance

RoHS

- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C (for TO-263AB package)
- Solder bath temperature 275 °C maximum, 10 s, per JESD 22-B106 (for TO-220AB, ITO-220AB, and TO-262AA package)
- · Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

TYPICAL APPLICATIONS

For use in high frequency converters, switching power supplies, freewheeling diodes, OR-ing diode, DC/DC converters and reverse battery protection.

MECHANICAL DATA

Case: TO-220AB, ITO-220AB, D2PAK (TO-263AB), and TO-262AA

Molding compound meets UL 94 V-0 flammability rating Base P/N-E3 - RoHS-compliant, commercial grade

Terminals: matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

E3 suffix meets JESD 201 class 1A whisker test

Polarity: as marked

Mounting Torque: 10 in-lbs maximum

MAXIMUM RATINGS (T _A = 25 °C unless otherwise noted)								
PARAMETER	SYMBOL	V30100S	VF30100S	VB30100S	VI30100S	UNIT		
Maximum repetitive peak reverse voltage	V_{RRM}	100			V			
Maximum average forward rectified current (fig. 1)	I _{F(AV)}	30				Α		
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load	I _{FSM}	250			Α			
Non-repetitive avalanche energy at T _J = 25 °C, L = 90 mH	E _{AS}	230			mJ			
Peak repetitive reverse current at $t_p = 2 \mu s$, 1 kHz, $T_J = 38 ^{\circ}C \pm 2 ^{\circ}C$	I _{RRM}	1.0		Α				
Voltage rate of change (rated V _R)	dV/dt	10 000		V/µs				
Isolation voltage (ITO-220AB only) from terminal to heatsink t = 1 min	V _{AC}	1500		V				
Operating junction and storage temperature range	T_J , T_{STG}	-40 to +150			°C			

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ELECTRICAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)							
PARAMETER	TEST CONDITIONS		SYMBOL	TYP.	MAX.	UNIT	
Breakdown voltage	I _R = 10 mA	T _A = 25 °C	V_{BR}	105 (minimum)	-	V	
Instantaneous forward voltage	I _F = 5 A	T _A = 25 °C	V _F ⁽¹⁾	0.47	-	V	
	I _F = 10 A			0.55	-		
	I _F = 30 A			0.80	0.91		
	I _F = 5 A	T _A = 125 °C		0.39	-		
	I _F = 10 A			0.49	-		
	I _F = 30 A			0.69	0.78		
Reverse current	V _R = 70 V	T _A = 25 °C	I _R ⁽²⁾	27	-	μΑ	
		T _A = 125 °C		11	-	mA	
	V _R = 100 V	T _A = 25 °C		70	1000	μΑ	
		T _A = 125 °C		23	45	mA	

Notes

⁽²⁾ Pulse test: Pulse width ≤ 40 ms

THERMAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)							
PARAMETER	SYMBOL	V30100S	VF30100S	VB30100S	VI30100S	UNIT	
Typical thermal resistance	$R_{\theta JC}$	2.0	4.0	2.0	2.0	°C/W	

ORDERING INFORMATION (Example)								
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE			
TO-220AB	V30100S-E3/4W	1.875	4W	50/tube	Tube			
ITO-220AB	VF30100S-E3/4W	1.805	4W	50/tube	Tube			
TO-263AB	VB30100S-E3/4W	1.380	4W	50/tube	Tube			
TO-263AB	VB30100S-E3/8W	1.380	8W	800/reel	Tape and reel			
TO-262AA	VI30100S-E3/4W	1.455	4W	50/tube	Tube			

RATINGS AND CHARACTERISTICS CURVES (T_A = 25 °C unless otherwise noted)

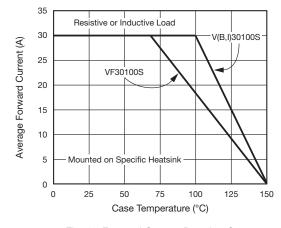


Fig. 1 - Forward Current Derating Curve

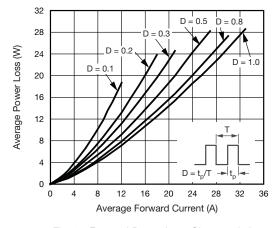


Fig. 2 - Forward Power Loss Characteristics

 $^{^{(1)}\,}$ Pulse test: 300 μs pulse width, 1 % duty cycle

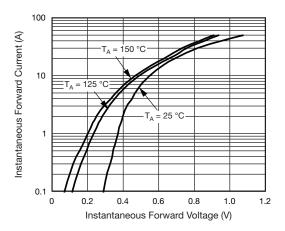


Fig. 3 - Typical Instantaneous Forward Characteristics

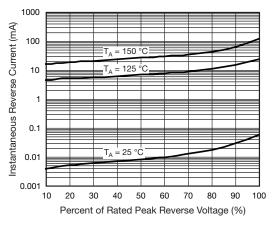


Fig. 4 - Typical Reverse Characteristics

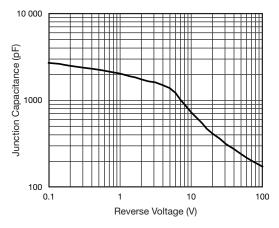


Fig. 5 - Typical Junction Capacitance

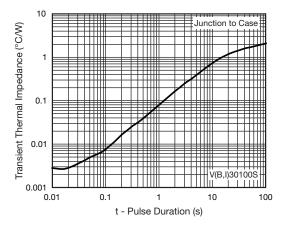


Fig. 6 - Typical Transient Thermal Impedance

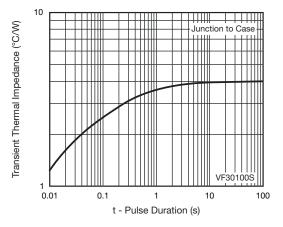
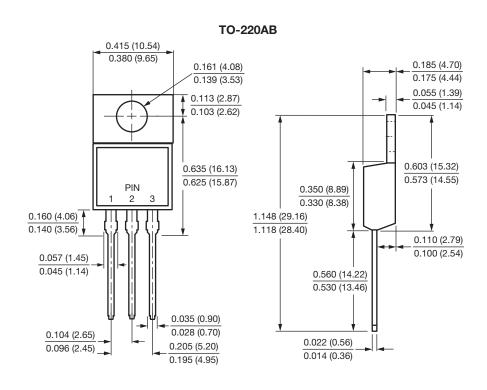


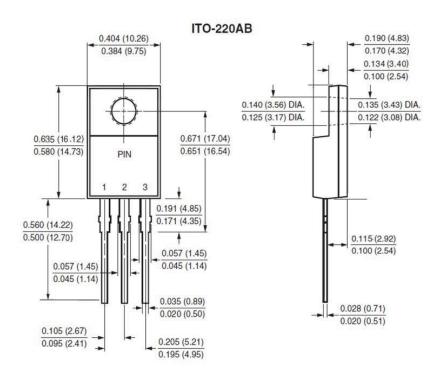
Fig. 7 - Typical Transient Thermal Impedance

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PACKAGE OUTLINE DIMENSIONS in inches (millimeters)

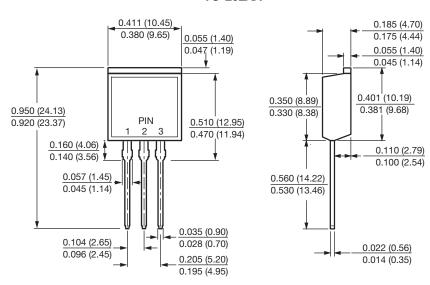
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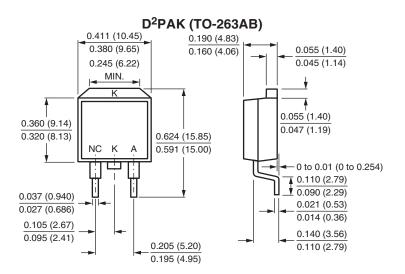




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TO-262AA





0.42 (10.66) MIN. 0.670 (17.02) 0.591 (15.00) 0.08 (2.032) MIN. 0.105 (2.67) 0.095 (2.41)



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